

To our customers,

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## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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**(5400 + 5400) PIXELS  $\times$  3 + COLOR CCD LINEAR IMAGE SENSOR**
**DESCRIPTION**

The  $\mu$ PD8874 is a color CCD (Charge Coupled Device) linear image sensor that changes optical images to electrical signal and has the function of color separation.

The  $\mu$ PD8874 has 3 rows of (5400 + 5400) staggered pixels, and each row has dual-sided readout type of charge transfer register. This product is high speed and High response version of the existing product  $\mu$ PD8873.

And it has reset feed-through level clamp circuits and voltage amplifiers. Therefore, it is suitable for 1200 dpi/A4 color image scanners, color MFP and so on.

**FEATURES**

- Valid photocell : (5400 + 5400) staggered pixels  $\times$  3
- Photocell's size :  $5.25 \times 5.25 \mu\text{m}$
- Line spacing : 63  $\mu\text{m}$  (12 lines) Red line - Green line, Green line - Blue line  
10.5  $\mu\text{m}$  (2 lines) Odd line - Even line (for each color)
- Color filter : High transmittance new color filter  
Primary colors (red, green and blue), pigment filter  
Light resistance  $10^7$  lx $\cdot$ hour with standard sunlight and ultraviolet cut filter (L40).
- Resolution : 48 dot/mm A4 (210  $\times$  297 mm) size (shorter side) for color  
1200 dpi US letter (8.5"  $\times$  11") size (shorter side) for color
- Drive clock level : CMOS output under 5 V operation
- Data rate : 20 MHz Max.
- Power supply : +12 V
- On-chip circuit : Reset feed-through level clamp circuits  
Voltage amplifiers

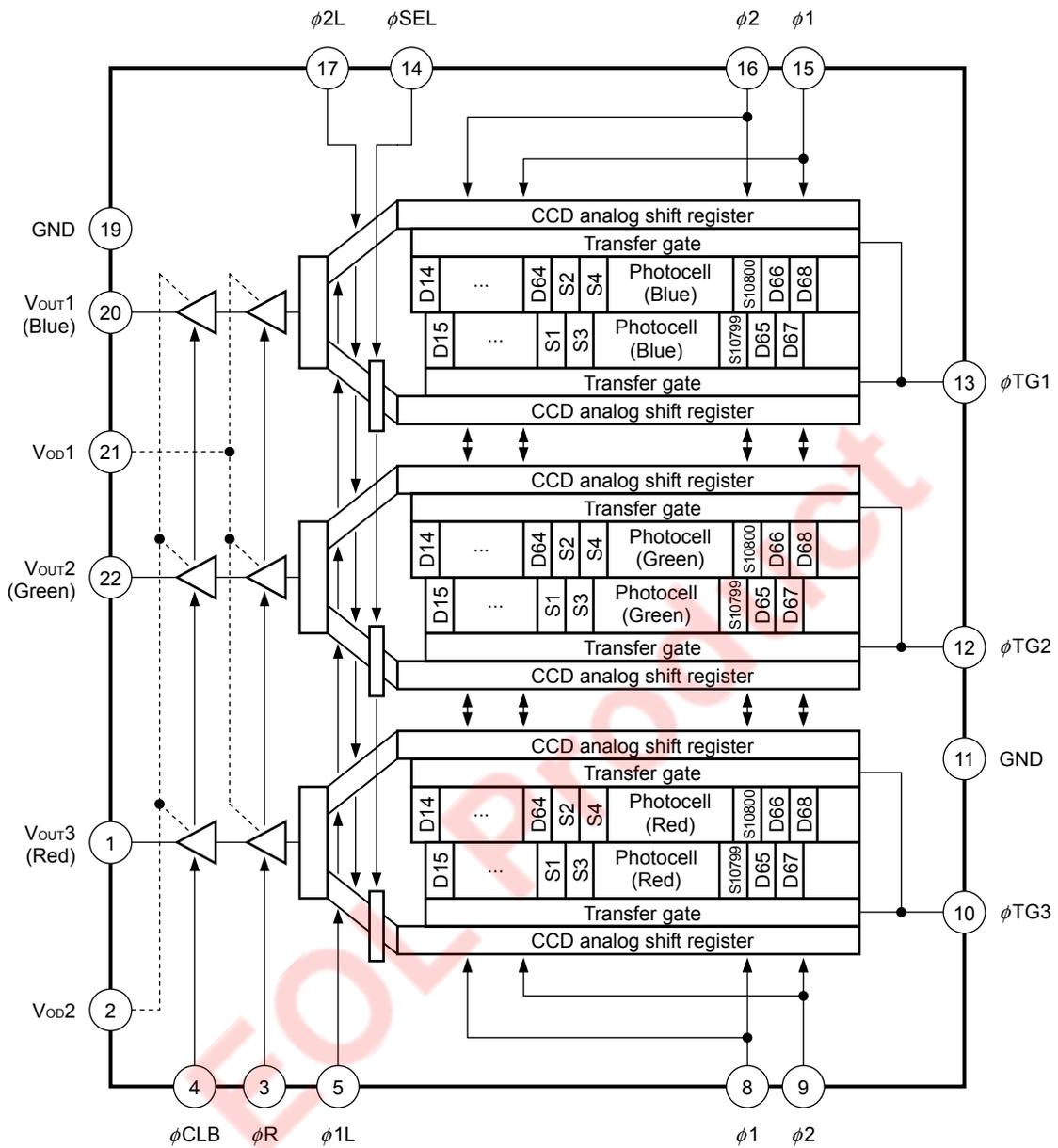
**ORDERING INFORMATION**

Part Number	Package
$\mu$ PD8874CY-A	CCD linear image sensor 22-pin plastic DIP (10.16 mm (400))

**Remark** The  $\mu$ PD8874CY-A is a lead-free product.

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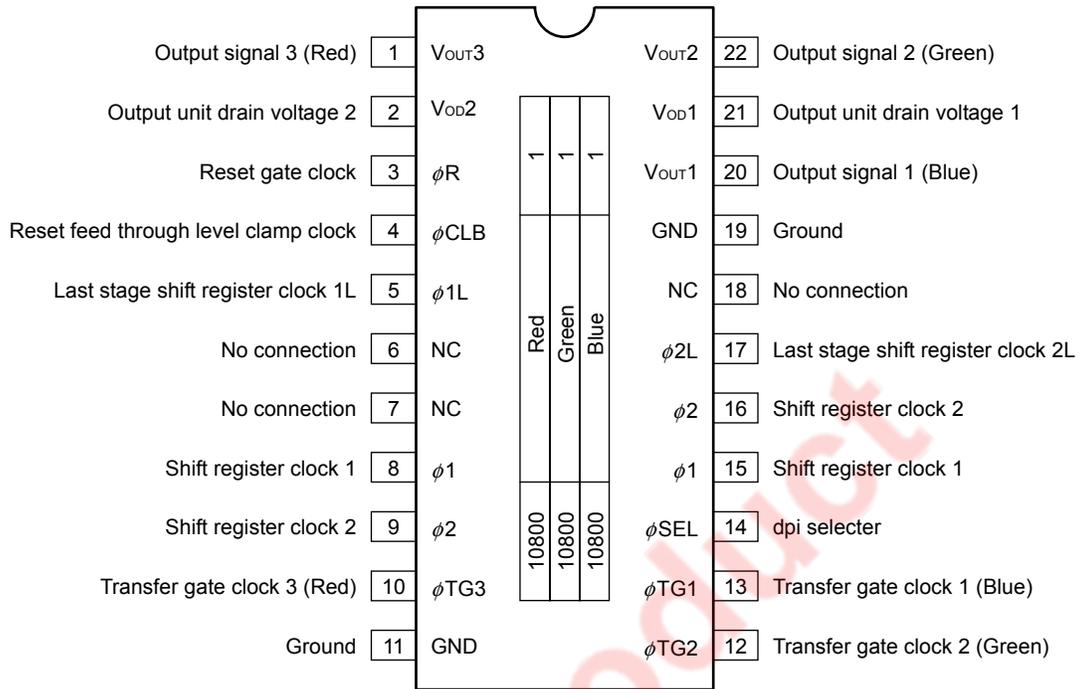
BLOCK DIAGRAM



**PIN CONFIGURATION (Top View)**

CCD linear image sensor 22-pin plastic DIP (10.16 mm (400))

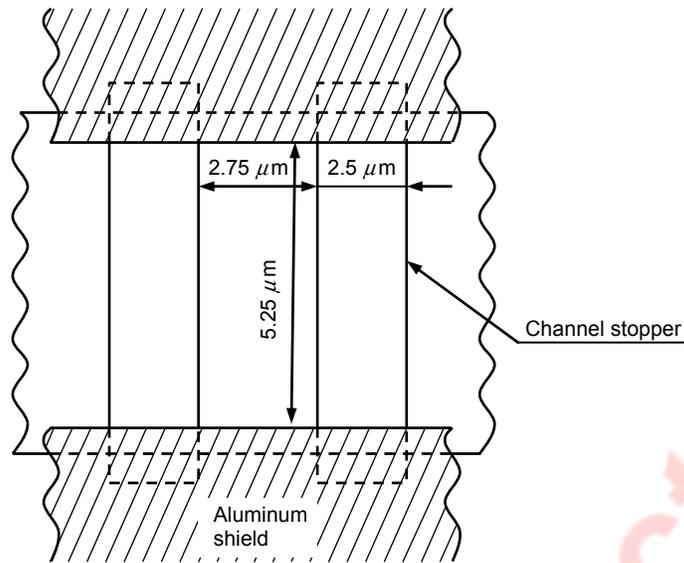
μPD8874CY-A



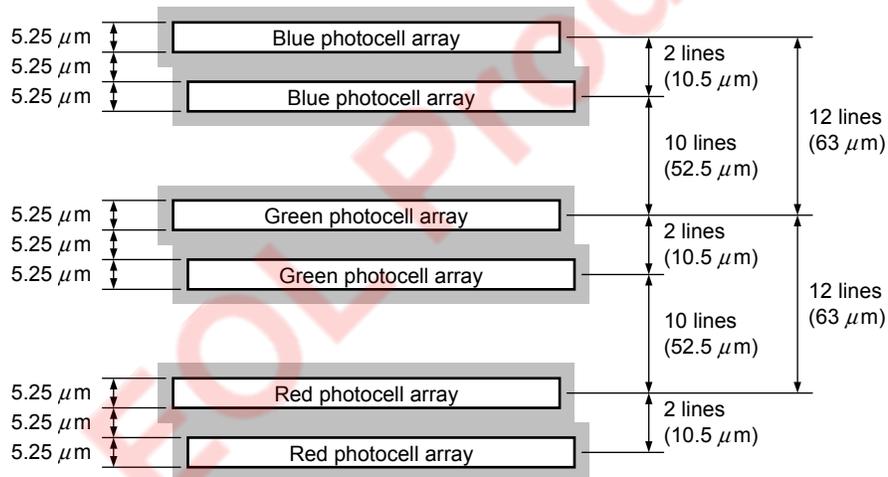
**Caution** Connect the no connection pins (NC) to GND.

EOL Product

PHOTOCELL STRUCTURE DIAGRAM



PHOTOCELL ARRAY STRUCTURE DIAGRAM (Line spacing)



**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = +25°C)**

Parameter	Symbol	Ratings	Unit
Output drain voltage	V <sub>OD1</sub> , V <sub>OD2</sub>	-0.3 to +15	V
Shift register clock voltage	V <sub>φ1</sub> , V <sub>φ2</sub>	-0.3 to +8	V
Last stage shift register clock voltage	V <sub>φ1L</sub> , V <sub>φ2L</sub>	-0.3 to +8	V
Reset gate clock voltage	V <sub>φR</sub>	-0.3 to +8	V
Reset feed-through level clamp clock voltage	V <sub>φCLB</sub>	-0.3 to +8	V
Dpi select signal voltage	V <sub>φSEL</sub>	-0.3 to +8	V
Transfer gate clock voltage	V <sub>φTG1</sub> to V <sub>φTG3</sub>	-0.3 to +8	V
Operating ambient temperature <sup>Note</sup>	T <sub>A</sub>	0 to +55	°C
Storage temperature	T <sub>stg</sub>	-40 to +70	°C

**Note** The operating ambient temperature T<sub>A</sub> is defined as an atmosphere temperature in a point 10 mm away on the substrate, and 10 mm away from the short side of package (pin 1 side). Use at the condition without dewy condensation.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**RECOMMENDED OPERATING CONDITIONS (T<sub>A</sub> = +25°C)**

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Output drain voltage	V <sub>OD1</sub> , V <sub>OD2</sub>	11.4	12.0	12.6	V
Shift register clock high level	V <sub>φ1H</sub> , V <sub>φ2H</sub>	4.75	5.0	5.5	V
Shift register clock low level	V <sub>φ1L</sub> , V <sub>φ2L</sub>	0	0	0.15	V
Last stage shift register clock high level	V <sub>φ1LH</sub> , V <sub>φ2LH</sub>	4.75	5.0	5.5	V
Last stage shift register clock low level	V <sub>φ1LL</sub> , V <sub>φ2LL</sub>	0	0	0.15	V
Reset gate clock high level	V <sub>φRH</sub>	4.75	5.0	5.5	V
Reset gate clock low level	V <sub>φRL</sub>	0	0	0.15	V
Reset feed-through level clamp clock high level	V <sub>φCLBH</sub>	4.75	5.0	5.5	V
Reset feed-through level clamp clock low level	V <sub>φCLBL</sub>	0	0	0.15	V
Dpi select signal high level	V <sub>φSELH</sub>	4.75	5.0	5.5	V
Dpi select signal low level	V <sub>φSELL</sub>	0	0	0.15	V
Transfer gate clock high level	V <sub>φTG1H</sub> to V <sub>φTG3H</sub>	4.75	V <sub>φ1H</sub> <sup>Note</sup>	V <sub>φ1H</sub> <sup>Note</sup>	V
Transfer gate clock low level	V <sub>φTG1L</sub> to V <sub>φTG3L</sub>	0	0	0.15	V
Data rate	f <sub>φR</sub>	–	2	20	MHz
Clock pulse frequency	f <sub>φ1</sub> , f <sub>φ2</sub>	–	2	20	MHz

**Note** When Transfer gate clock high level (V<sub>φTG1H</sub> to V<sub>φTG3H</sub>) is higher than Shift register clock high level (V<sub>φ1H</sub>), Image lag increases.

**ELECTRICAL CHARACTERISTICS**

( $T_A = +25^\circ\text{C}$ ,  $V_{OD} = 12\text{ V}$ , data rate ( $f_{\phi R}$ ) = 2 MHz, storage time = 5.5 ms, input signal clock = 5 V<sub>p-p</sub>  
light source: 3200 K halogen lamp + C-500S (infrared cut filter, t = 1 mm)+ HA-50 (heat absorbing filter, t = 3 mm)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Saturation voltage	V <sub>sat</sub>		2.0	2.5	–	V
Saturation exposure	Red	SER	–	0.25	–	lx•s
	Green	SEG	–	0.27	–	lx•s
	Blue	SEB	–	0.5	–	lx•s
Photo response non-uniformity	PRNU	V <sub>OUT</sub> = 1.0 V	–	6	20	%
Average dark signal	ADS	Light shielding	–	0.2	2.0	mV
Dark signal non-uniformity	DSNU	Light shielding	–	1.5	5.0	mV
Total power consumption	P <sub>w</sub>	Light shielding	–	360	540	mW
Output impedance	Z <sub>o</sub>		–	0.2	0.4	kΩ
Response	Red	R <sub>R</sub>	7.0	10.0	13.0	V/lx•s
	Green	R <sub>G</sub>	6.3	9.0	11.7	V/lx•s
	Blue	R <sub>B</sub>	3.5	5.0	6.5	V/lx•s
Image lag	IL	V <sub>OUT</sub> = 1.0 V	–	3.0	7.0	%
Offset level	V <sub>os</sub>		6.5	7.5	8.5	V
Output fall delay time <sup>Note</sup>	t <sub>d</sub>	V <sub>OUT</sub> = 1.0 V	–	15	–	ns
Total transfer efficiency <sup>Note</sup>	TTE	V <sub>OUT</sub> = 1.0 V, data rate = 20 MHz	92	98	–	%
Register imbalance	RI	V <sub>OUT</sub> = 1.0 V	–	1.0	4.0	%
Response peak	Red		–	610	–	nm
	Green		–	535	–	nm
	Blue		–	460	–	nm
Dynamic range	DR1	V <sub>sat</sub> / DSNU	–	1666	–	times
	DR2	V <sub>sat</sub> / σ <sub>dark</sub>	–	1041	–	times
Reset feed-through noise	RFTN	Light shielding	–2000	–100	+500	mV
	PRFTN	Light shielding, t <sub>4</sub> and t <sub>5</sub> = 2 ns	–	500	800	mV
Random noise	σ <sub>dark</sub>	Light shielding, Bit clamp (t <sub>11</sub> > 10 ns)	–	2.4	–	mV

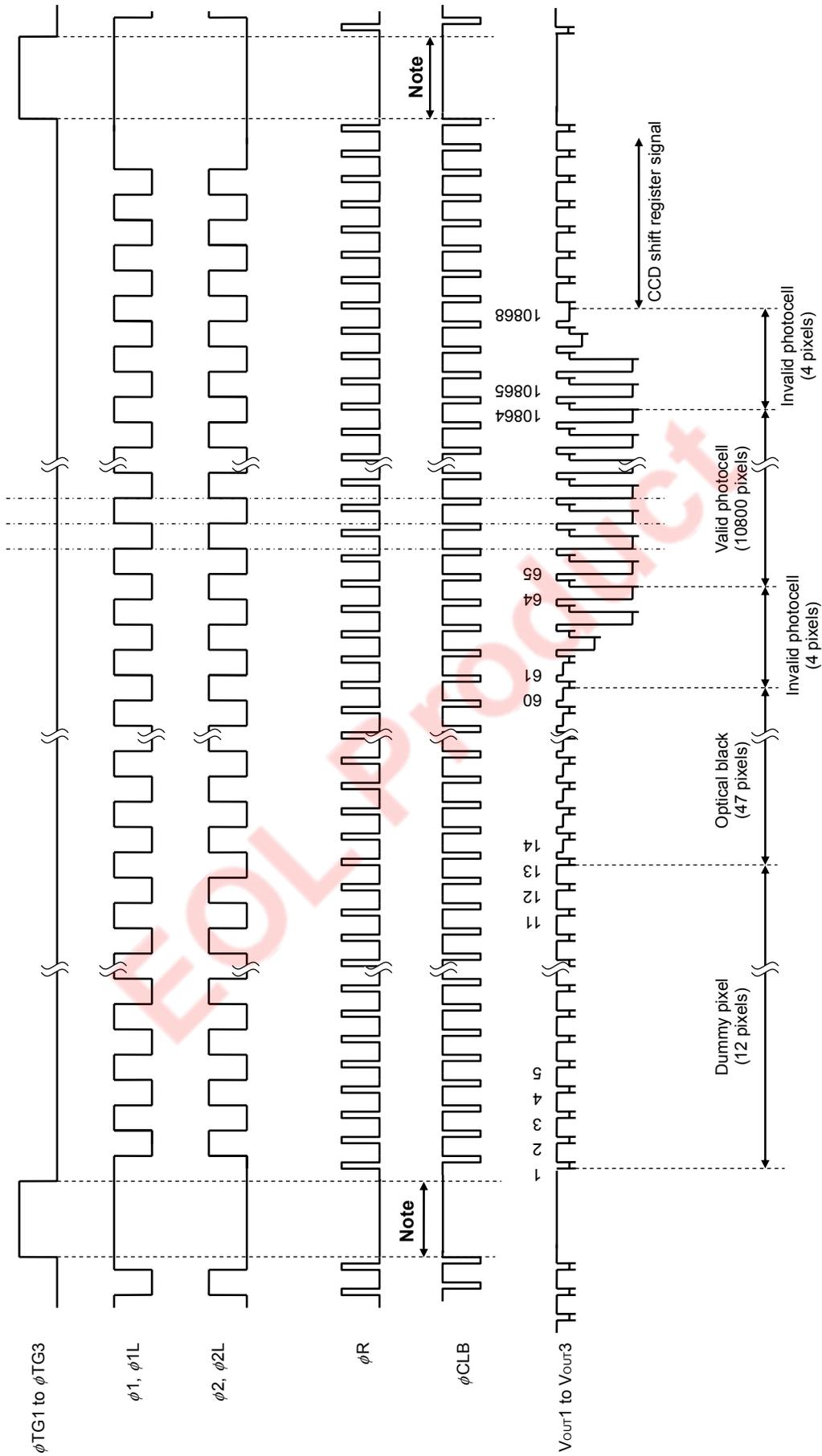
**Note** When the fall time of φ1L and φ2L (t1L and t2L) is the typical value (refer to **TIMING CHART 2-1 to 2-3**).

INPUT PIN CAPACITANCE ( $T_A = +25^\circ\text{C}$ ,  $V_{OD} = 12\text{ V}$ )

Parameter	Symbol	Pin name	Pin No.	MIN.	TYP.	MAX.	Unit
Shift register clock pin capacitance 1	$C_{\phi 1}$	$\phi 1$	8	–	550	–	pF
			15	–	550	–	pF
	$C_{\phi 1}$ total capacitance			–	1100	–	pF
Shift register clock pin capacitance 2	$C_{\phi 2}$	$\phi 2$	9	–	550	–	pF
			16	–	550	–	pF
	$C_{\phi 2}$ total capacitance			–	1100	–	pF
Last stage shift register clock pin capacitance 1	$C_{\phi 1L}$	$\phi 1L$	5	–	10	–	pF
Last stage shift register clock pin capacitance 2	$C_{\phi 2L}$	$\phi 2L$	17	–	10	–	pF
Reset gate clock pin capacitance	$C_{\phi R}$	$\phi R$	3	–	10	–	pF
Reset feed-through level clamp clock pin capacitance	$C_{\phi CLB}$	$\phi CLB$	4	–	10	–	pF
Dpi select signal pin capacitance	$C_{\phi SEL}$	$\phi SEL$	14	–	10	–	pF
Transfer gate clock pin capacitance	$C_{\phi TG}$	$\phi TG1$	13	–	100	–	pF
		$\phi TG2$	12	–	100	–	pF
		$\phi TG3$	10	–	100	–	pF

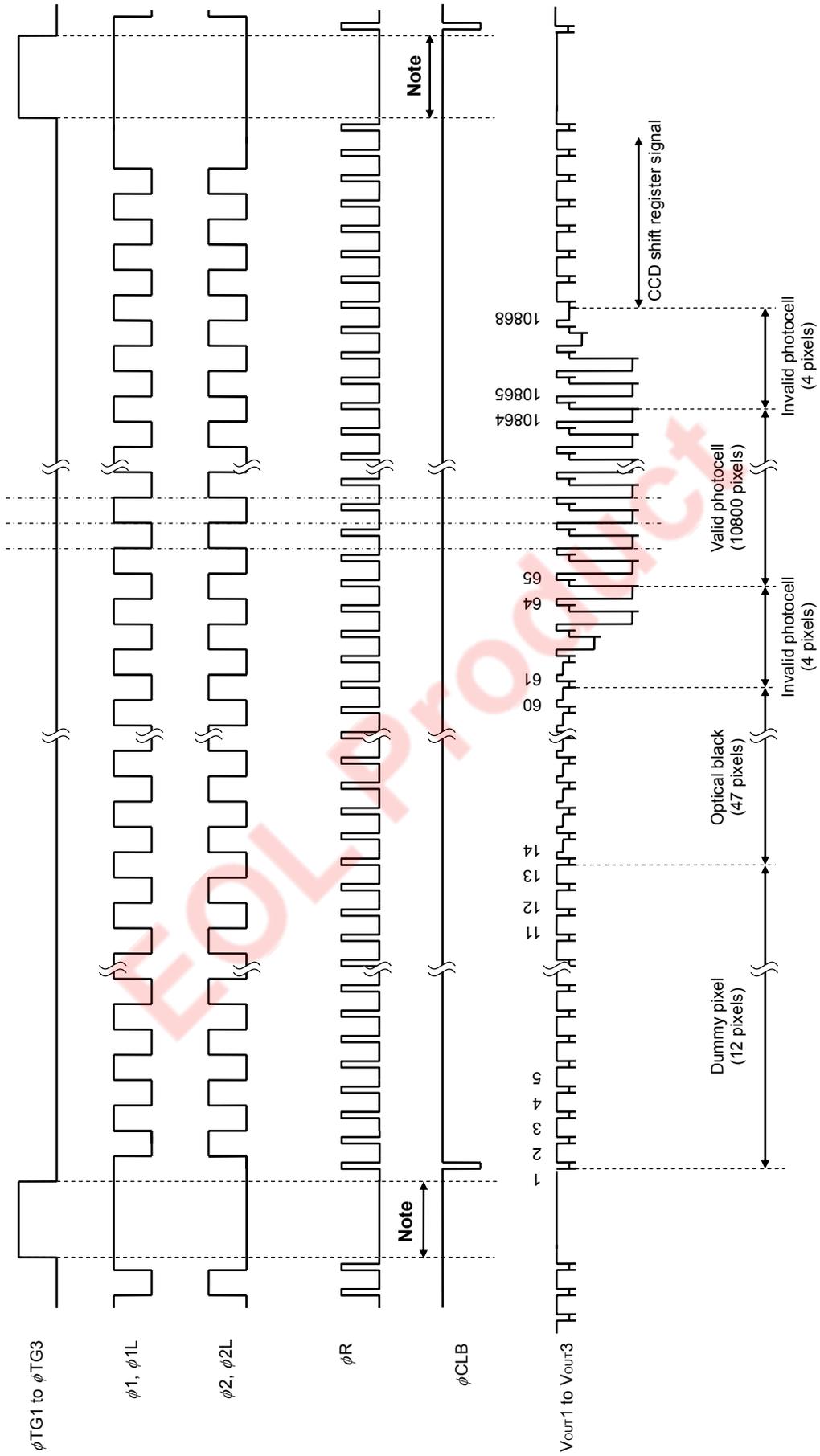
- Remarks**
- Pin 8, 15 ( $\phi 1$ ) and pin 9, 16 ( $\phi 2$ ) are each connected inside of the device.
  - $C_{\phi 1}$  and  $C_{\phi 2}$  show the equivalent capacity of the real drive including the capacity of between  $\phi 1$  and  $\phi 2$ .

**TIMING CHART 1-1 (for each color, 1200 dpi, φSEL = high, bit clamp mode)**



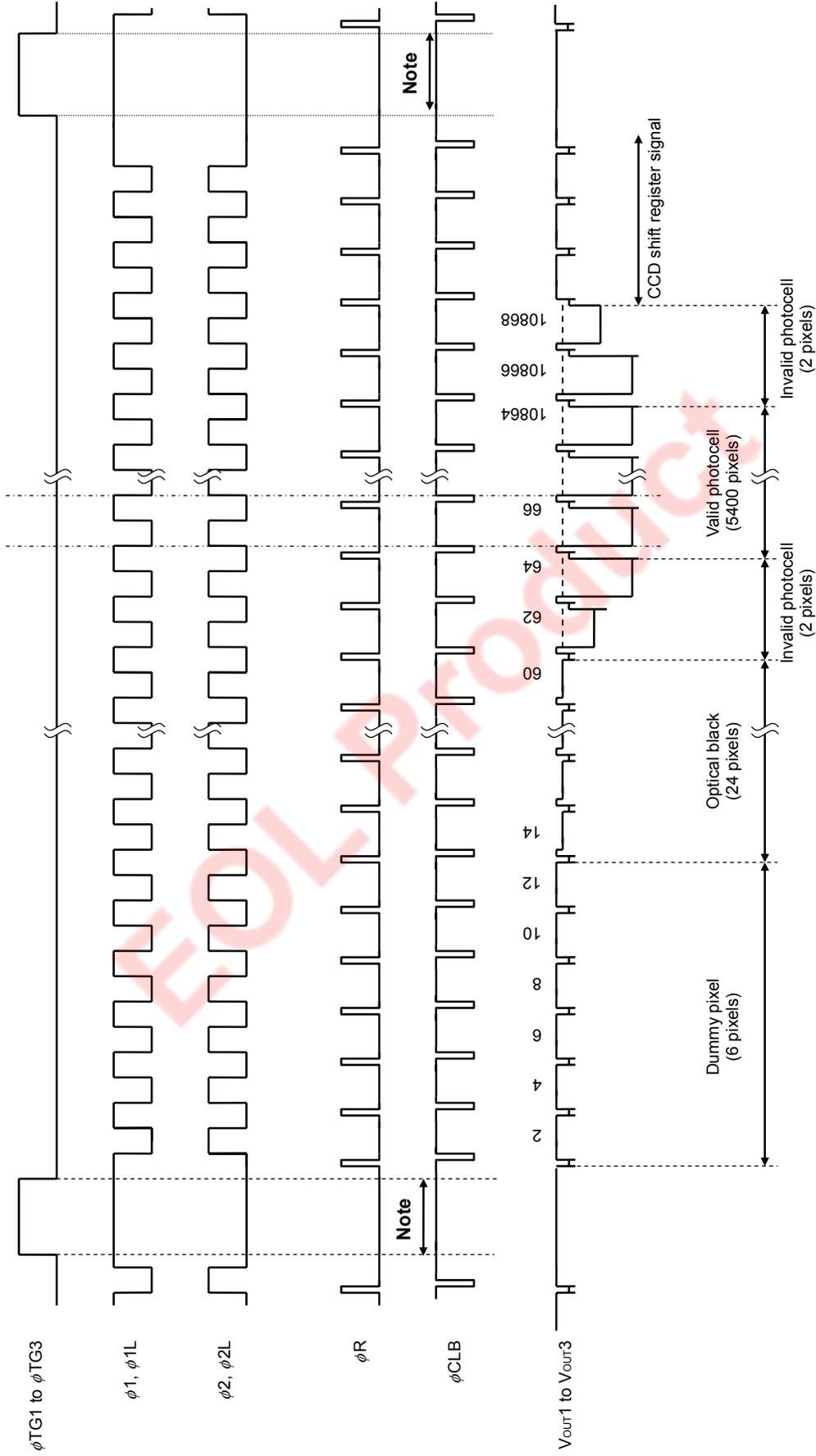
**Note** Set the  $\phi_R$  to low level and  $\phi_{CLB}$  to high level during this period.

**TIMING CHART 1-2 (for each color, 1200 dpi, φSEL = high, line clamp mode)**



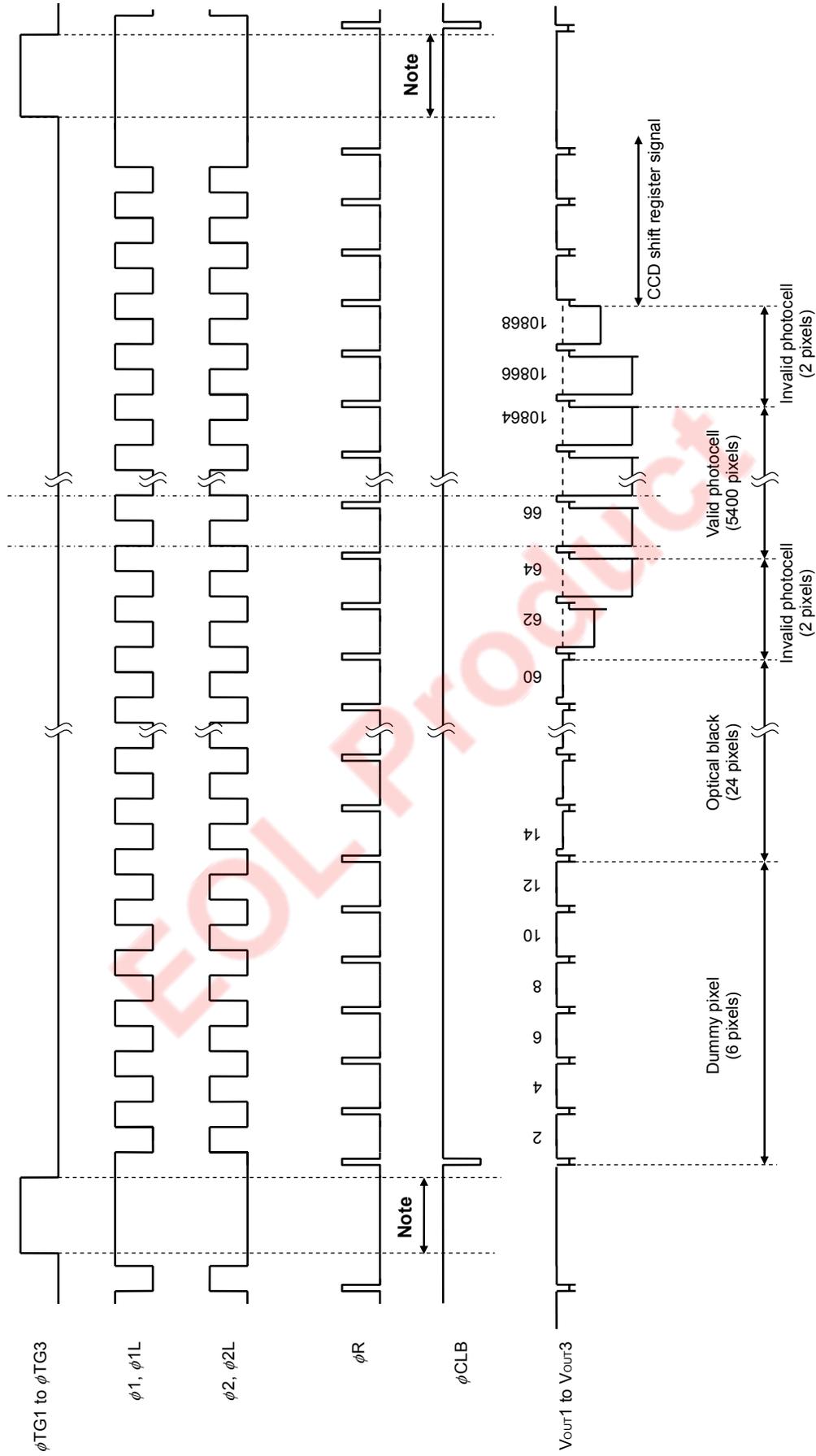
**Note** Set the  $\phi_R$  to low level and  $\phi_{CLB}$  to high level during this period.

**TIMING CHART 1-3 (for each color, 600 dpi, φSEL = low, bit clamp mode)**

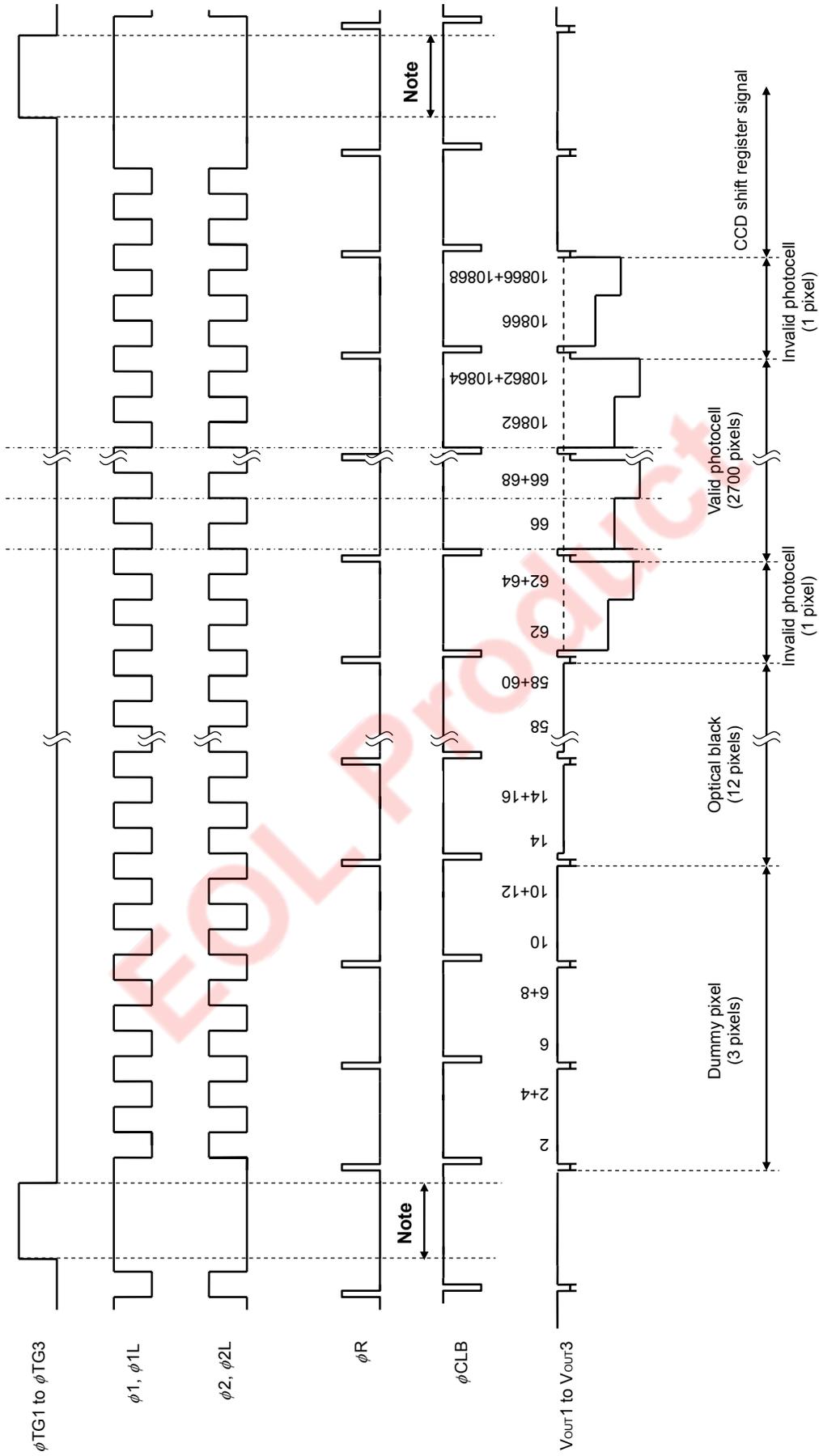


**Note** Set the  $\phi_R$  to low level and  $\phi_{CLB}$  to high level during this period.

**TIMING CHART 1-4 (for each color, 600 dpi, φSEL = low, line clamp mode)**



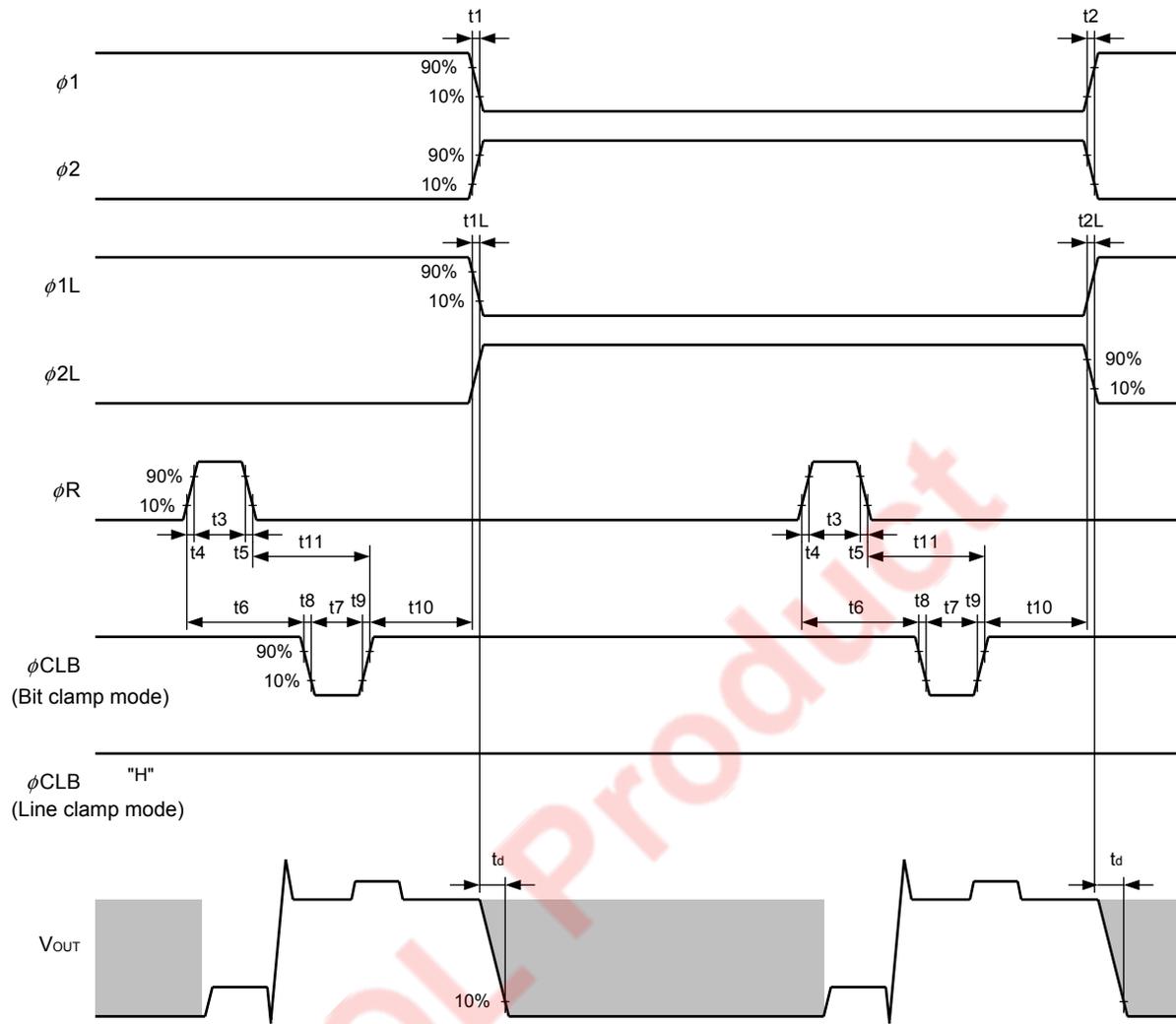
**TIMING CHART 1-5 (for each color, 300 dpi, φSEL = low, bit clamp mode)**



**Note** Set the  $\phi_R$  to low level and  $\phi_{CLB}$  to high level during this period.



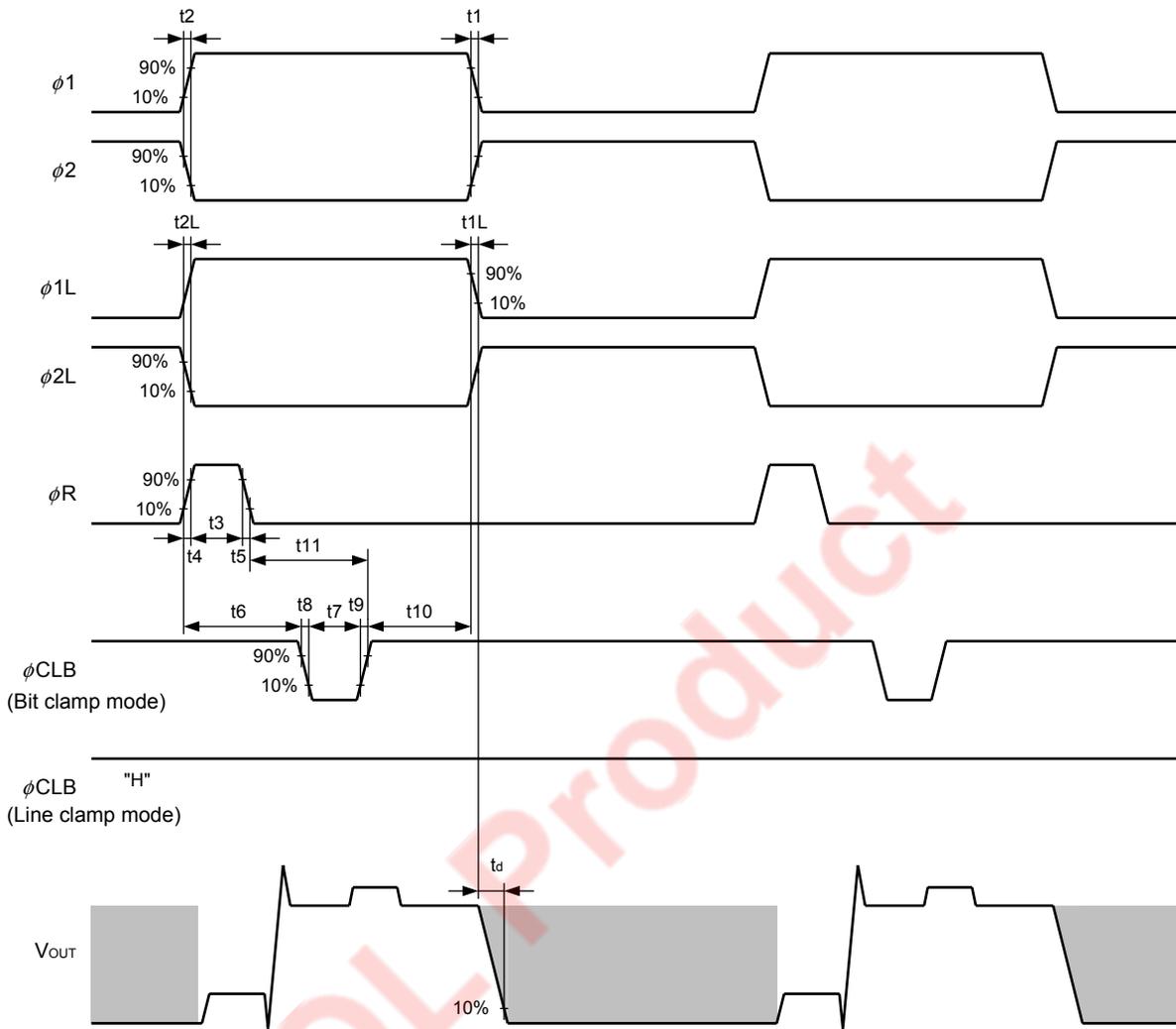
TIMING CHART 2-1 (1200 dpi, for each color)



Symbol	MIN.	TYP. <sup>Note</sup>	MAX.	Unit
t1, t2	0	15	–	ns
t1L, t2L	0	5	–	ns
t3	5	50	–	ns
t4, t5	0	5	–	ns
t6	0	70	–	ns
t7	10	50	–	ns
t8, t9	0	5	–	ns
t10	0	45	–	ns
t11	10	50	–	ns

**Note** TYP. is the case of  $\phi R = 2$  MHz

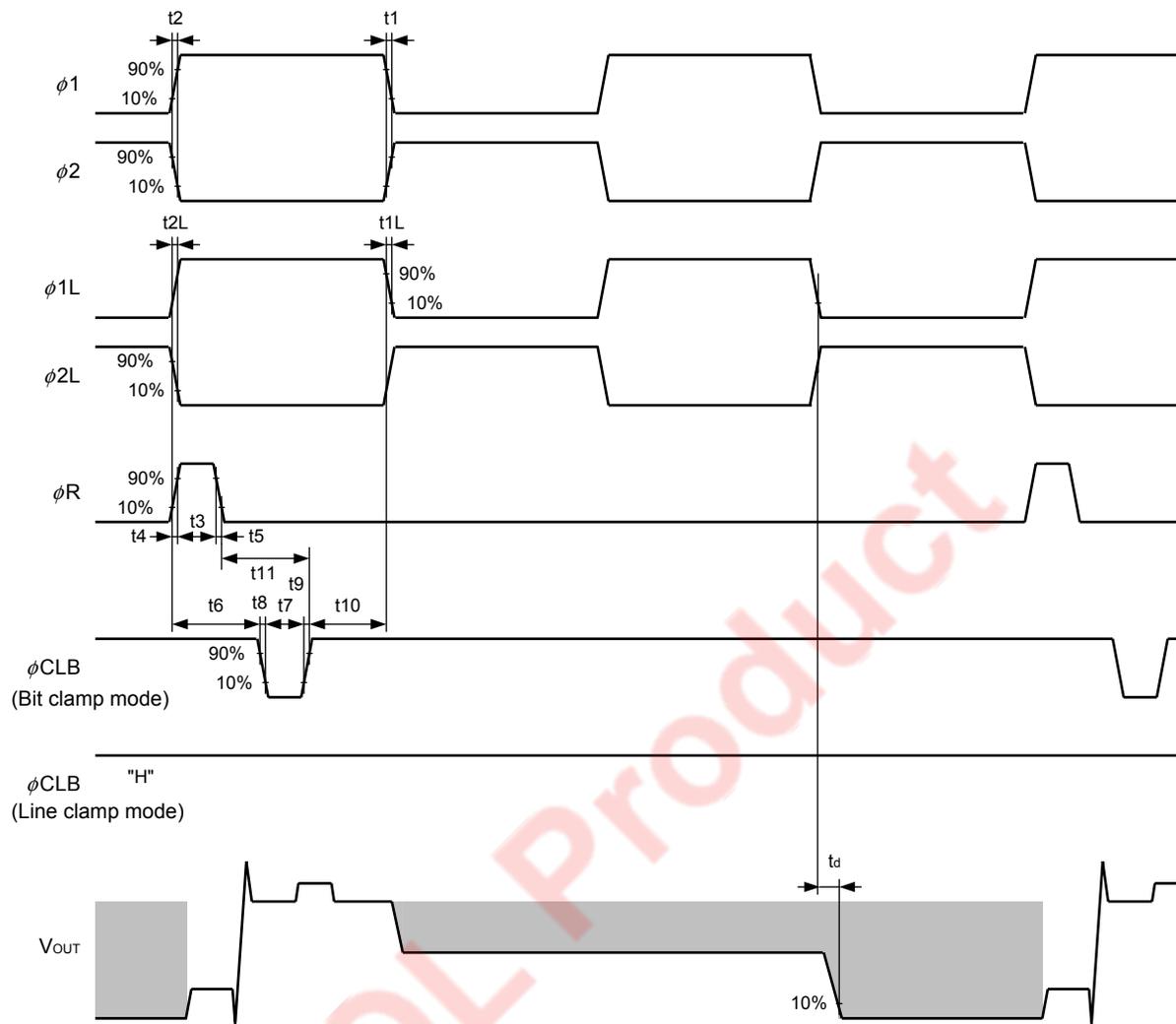
TIMING CHART 2-2 (600 dpi, for each color)



Symbol	MIN.	TYP. <sup>Note</sup>	MAX.	Unit
t1, t2	0	15	–	ns
t1L, t2L	0	5	–	ns
t3	5	50	–	ns
t4, t5	0	5	–	ns
t6	0	70	–	ns
t7	10	50	–	ns
t8, t9	0	5	–	ns
t10	0	45	–	ns
t11	10	50	–	ns

**Note** TYP. is the case of  $\phi R = 2$  MHz

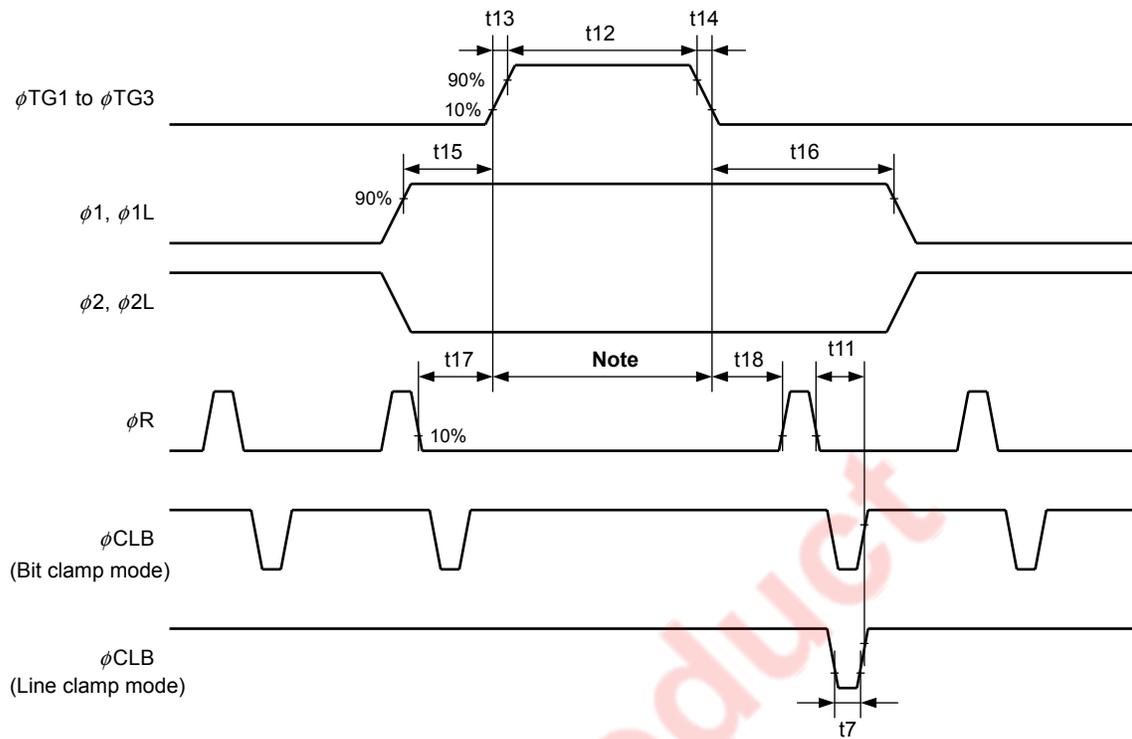
TIMING CHART 2-3 (300 dpi, for each color)



Symbol	MIN.	TYP. <sup>Note</sup>	MAX.	Unit
t1, t2	0	15	–	ns
t1L, t2L	0	5	–	ns
t3	5	50	–	ns
t4, t5	0	5	–	ns
t6	0	70	–	ns
t7	10	50	–	ns
t8, t9	0	5	–	ns
t10	0	45	–	ns
t11	10	50	–	ns

**Note** TYP. is the case of  $\phi R = 1$  MHz

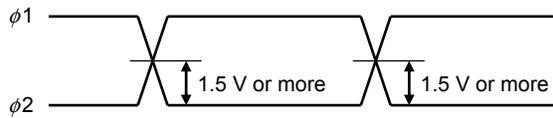
φTG1 to φTG3, φ1, φ2 TIMING CHART



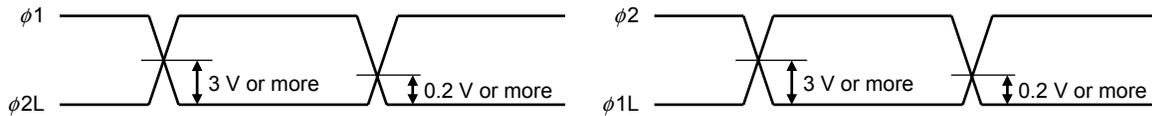
Symbol	MIN.	TYP.	MAX.	Unit
t7	10	50	-	ns
t11	10	50	-	ns
t12	5000	10000	50000	ns
t13, t14	0	50	-	ns
t15, t16	900	1000	-	ns
t17, t18	200	400	-	ns

**Note** Set the  $\phi R$  to low level and  $\phi CLB$  to high level during this period.

**φ1, φ2 cross points**

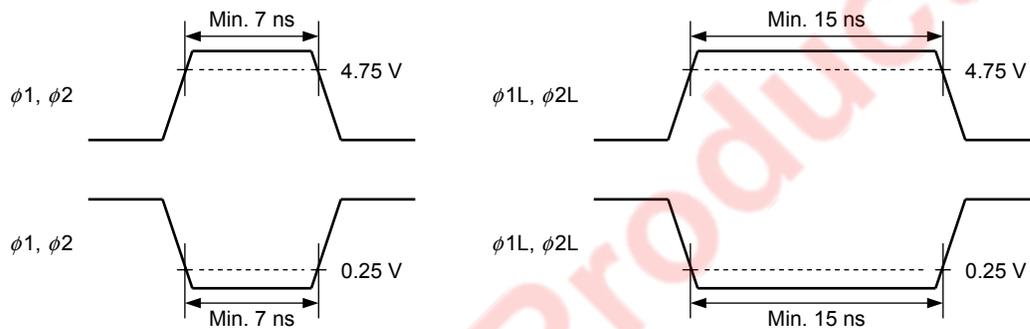


**φ1, φ2L cross points, φ2, φ1L cross points**

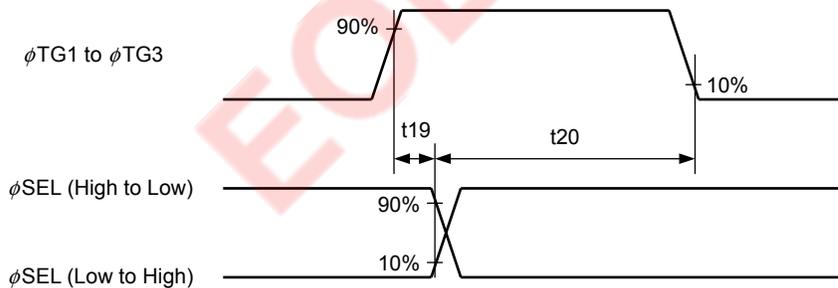


**Remark** Adjust cross points (φ1, φ2), (φ1L, φ2) and (φ1, φ2L) with input resistance of each pin.

**φ1, φ2, φ1L, φ2L clock width**



**φTG, φSEL TIMING CHART**



Symbol	MIN.	TYP.	MAX.	Unit
t19	0	0	–	ns
t20	4500	9500	–	ns

**SELECTION OF RESOLUTION MODE**

The μPD8874 has function of two readout modes, High Resolution Mode and Low Resolution Mode. These two modes can be selected by φSEL switch.

Read Mode	Description	φSEL
High Resolution Mode	1200 dpi (Max.)	High level
Low Resolution Mode	600 dpi (Max.) (even line readout mode)	Low level

**(1) High Resolution Mode**

In this mode, both signals in even lines and odd lines can be read out. This mode enables 1200 dpi (Max.) resolution with A4 size (210 × 297 mm, shorter side).

Please refer to **TIMING CHART 1-1, 1-2 and 2-1**.

**(2) Low Resolution Mode**

In this mode, only signal in even lines can be read out.

This mode enables 600 dpi (Max.) resolution with A4 size.

To use intermittent reset drive enable signal charges of adjacent pixels in even line to add at the charge to voltage conversion area. Then it can achieve low resolution with A4 size such as 300, 200 or 150 dpi.

Please refer to **TIMING CHART 1-3 to 1-6, 2-2 and 2-3**.

EOL Product

**DEFINITIONS OF CHARACTERISTIC ITEMS**

**1. Saturation voltage :  $V_{sat}$**

Output signal voltage at which the response linearity is lost.

**2. Saturation exposure : SE**

Product of intensity of illumination (lx) and storage time (s) when saturation of output voltage occurs.

**3. Photo response non-uniformity : PRNU**

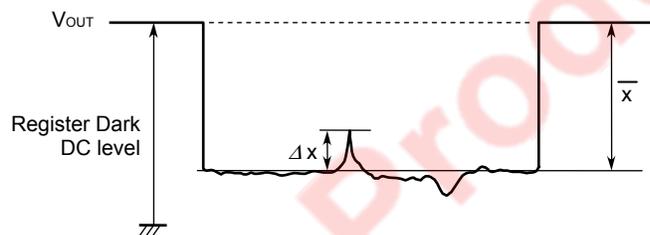
The output signal non-uniformity of all the valid pixels when the photosensitive surface is applied with the light of uniform illumination. This is calculated by the following formula.

$$PRNU (\%) = \frac{\Delta x}{\bar{x}} \times 100$$

$\Delta x$  : maximum of  $|x_j - \bar{x}|$

$$\bar{x} = \frac{\sum_{j=1}^{10800} x_j}{10800}$$

$x_j$  : Output voltage of valid pixel number j



**4. Average dark signal : ADS**

Average output signal voltage of all the valid pixels at light shielding. This is calculated by the following formula.

$$ADS (mV) = \frac{\sum_{j=1}^{10800} d_j}{10800}$$

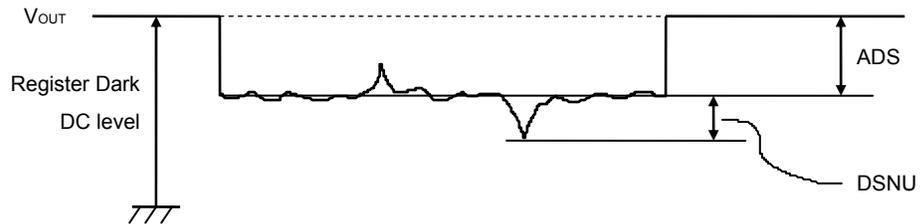
$d_j$  : Dark signal of valid pixel number j

**5. Dark signal non-uniformity : DSNU**

Absolute maximum of the difference between ADS and voltage of the highest or lowest output pixel of all the valid pixels at light shielding. This is calculated by the following formula.

$$\text{DSNU (mV)} : \text{maximum of } |d_j - \text{ADS}| \text{ } j = 1 \text{ to } 10800$$

$d_j$  : Dark signal of valid pixel number  $j$



**6. Output impedance : Zo**

Impedance of the output pins viewed from outside.

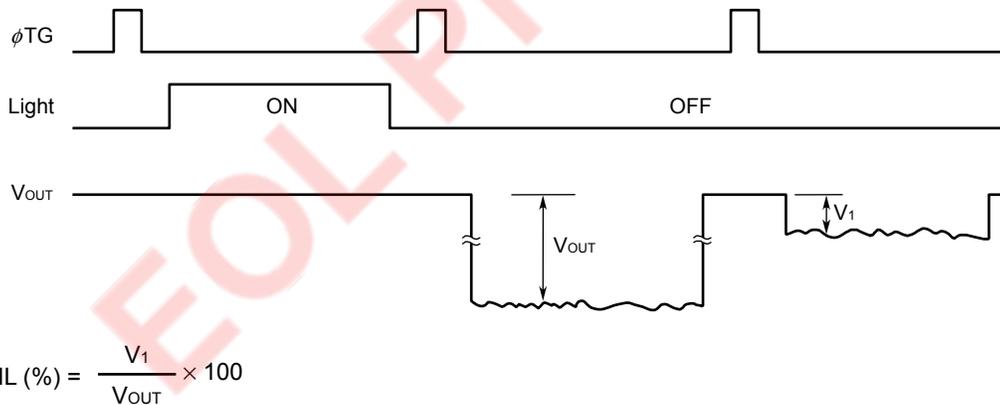
**7. Response : R**

Output voltage divided by exposure ( $I \times s$ ).

Note that the response varies with a light source (spectral characteristic).

**8. Image lag : IL**

The rate between the last output voltage and the next one after read out the data of a line.



**9. Register imbalance : RI**

The rate of the difference between the averages of the output voltage of Odd and Even pixels, against the average output voltage of all the valid pixels.

$$RI (\%) = \frac{\frac{2}{n} \left| \sum_{j=1}^{\frac{n}{2}} (V_{2j-1} - V_{2j}) \right|}{\frac{1}{n} \sum_{j=1}^n V_j} \times 100$$

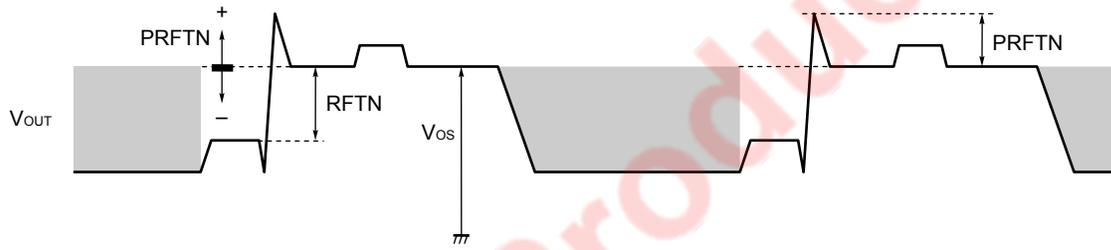
n : Number of valid pixels  
 V<sub>j</sub> : Output voltage of each pixel

**10. Offset level : VOS**

DC level of output signal is defined as follows.

**11. Reset feed-through noise : RFTN, PRFTN**

Reset feed-through noise (RFTN) and peak of RFTN (PRFTN) are defined as follows.

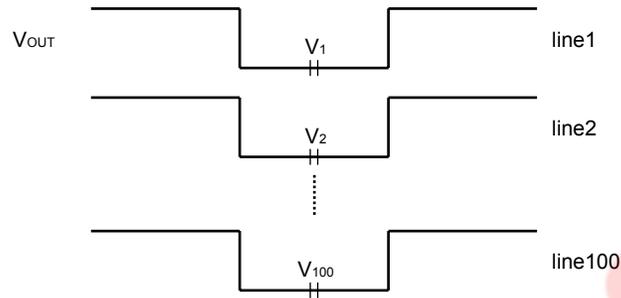


**12. Light shielding random noise: σ dark**

Light shielding random noise σ dark is defined as the standard deviation of a valid pixel output signal with 100 times (= 100 lines) data sampling at dark (light shielding).

$$\sigma \text{ (mV)} = \sqrt{\frac{\sum_{i=1}^{100} (V_i - \bar{V})^2}{100}}, \quad \bar{V} = \frac{1}{100} \sum_{i=1}^{100} V_i$$

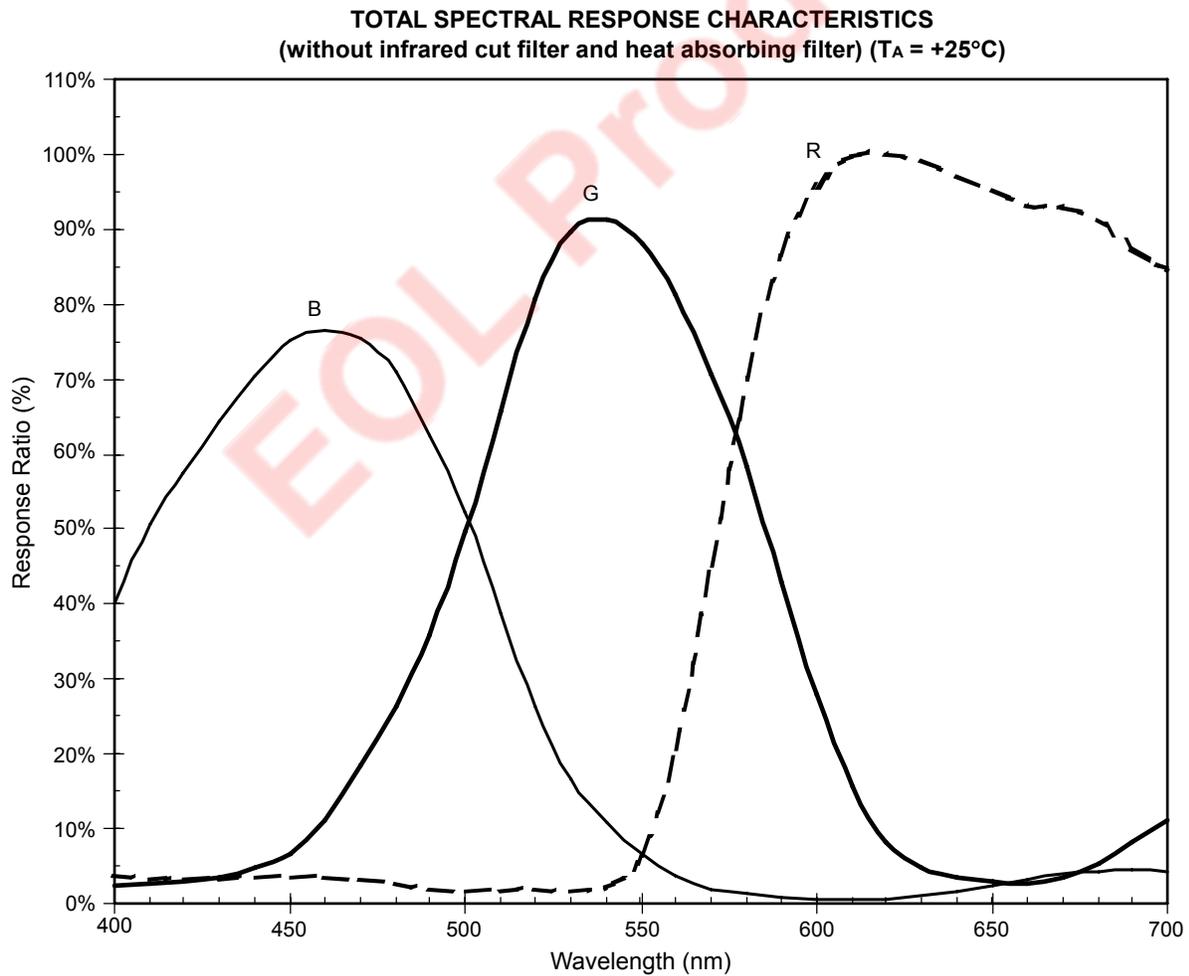
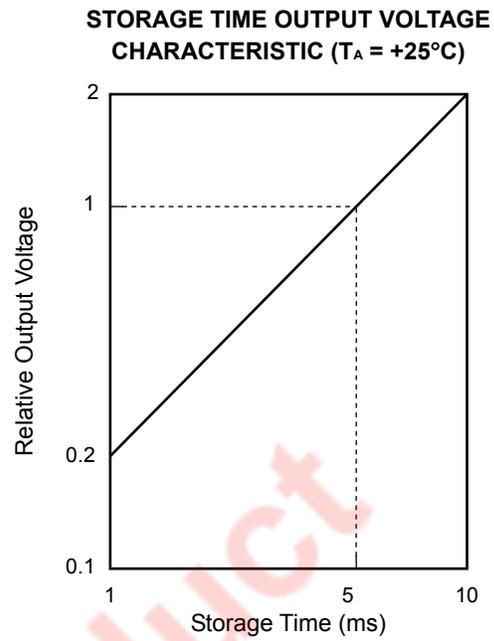
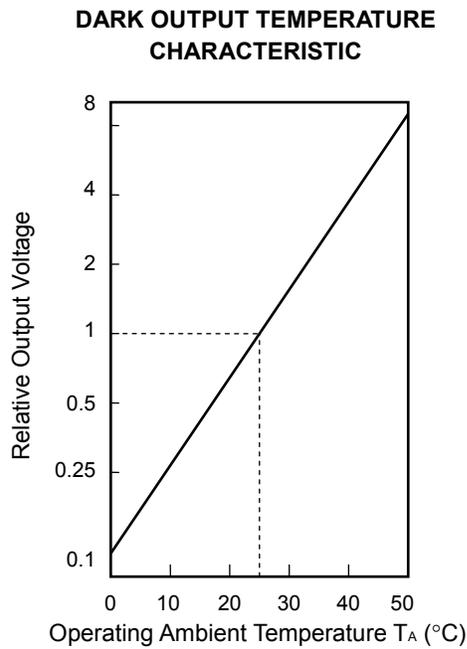
V<sub>i</sub> : A valid pixel output signal among all of the valid pixels for each



**Remark** This is measured by the DC level sampling of only the signal level, not by CDS (Correlated Double Sampling)

EOL Product

STANDARD CHARACTERISTIC CURVES (Reference Value)

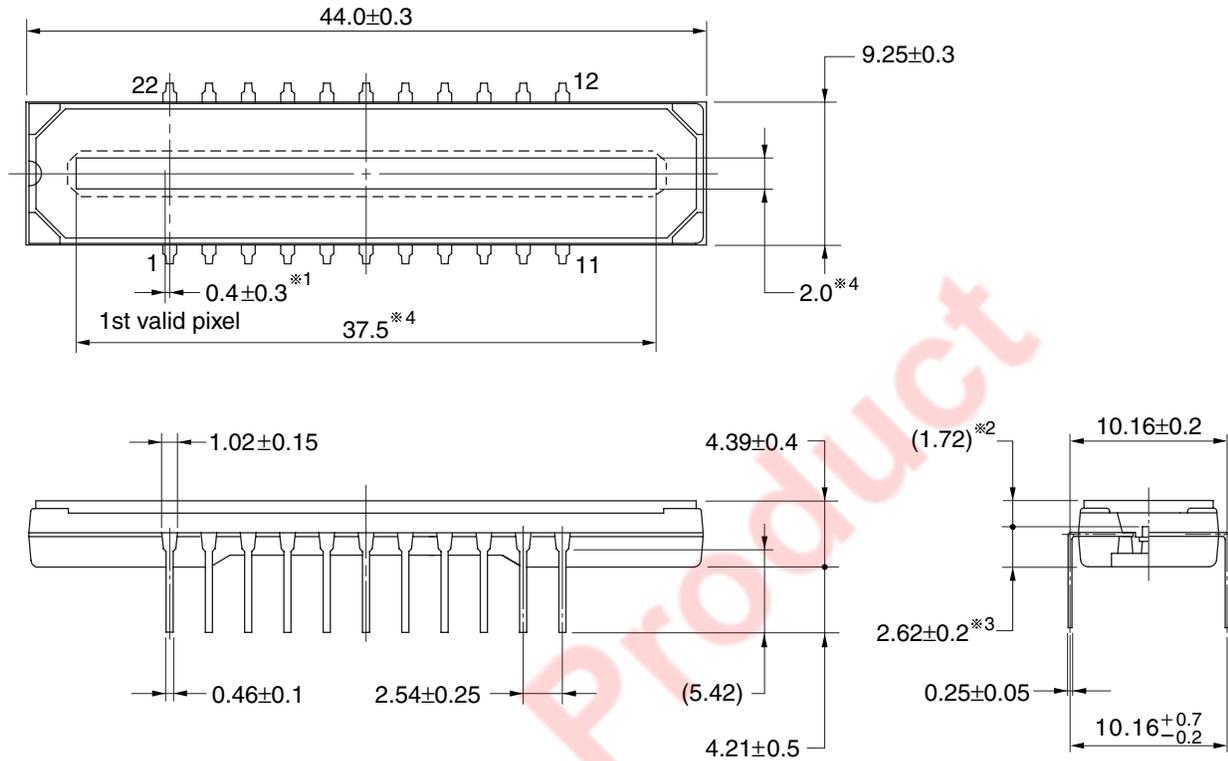




PACKAGE DRAWING

μPD8874CY-A  
 CCD LINEAR IMAGE SENSOR 22-PIN PLASTIC DIP (10.16 mm (400))

(Unit : mm)



Name	Dimensions	Refractive index
Plastic cap	42.7×8.35×0.8(0.7*5)	1.5

- ※1 Distance between the 1st valid pixel and the center of the pin1
- ※2 Distance between the top of the cap and the surface of the CCD chip
- ※3 Distance between the bottom of the package and the surface of the CCD chip
- ※4 Transparent window
- ※5 Thickness of the transparent window

22C-1CCD-PKG19

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**RECOMMENDED SOLDERING CONDITIONS**

When soldering this product, it is highly recommended to observe the conditions as shown below.

If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

**Type of Through-hole Device**

**μPD8874CY-A: CCD linear image sensor 22-pin plastic DIP (10.16 mm (400))**

Process	Conditions
Partial heating method	Pin temperature: 380°C or below, Heat time: 3 seconds or less (per pin).

- Cautions**
1. **During assembly care should be taken to prevent solder or flux from contacting the plastic cap. The optical characteristics could be degraded by such contact.**
  2. **Soldering by the solder flow method may have deleterious effects on prevention of plastic cap soiling and heat resistance. So the method cannot be guaranteed.**

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**NOTES ON HANDLING THE PACKAGES**

**① DUST AND DIRT PROTECTING**

The optical characteristics of the CCD will be degraded if the cap is scratched during cleaning. Don't either touch plastic cap surface by hand or have any object come in contact with plastic cap surface. Should dirt stick to a plastic cap surface, blow it off with an air blower. For dirt stuck through electricity ionized air is recommended. And if the plastic cap surface is grease stained, clean with our recommended solvents.

**○ CLEANING THE PLASTIC CAP**

Care should be taken when cleaning the surface to prevent scratches.

We recommend cleaning the cap with a soft cloth moistened with one of the recommended solvents below. Excessive pressure should not be applied to the cap during cleaning. If the cap requires multiple cleanings it is recommended that a clean surface or cloth be used.

**○ RECOMMENDED SOLVENTS**

The following are the recommended solvents for cleaning the CCD plastic cap.

Use of solvents other than these could result in optical or physical degradation in the plastic cap. Please consult your sales office when considering an alternative solvent.

Solvents	Symbol
Ethyl Alcohol	EtOH
Methyl Alcohol	MeOH
Isopropyl Alcohol	IPA
N-methyl Pyrrolidone	NMP

**② MOUNTING OF THE PACKAGE**

The application of an excessive load to the package may cause the package to warp or break, or cause chips to come off internally. Particular care should be taken when mounting the package on the circuit board. Don't have any object come in contact with plastic cap. You should not reform the lead frame. We recommended to use a IC-inserter when you assemble to PCB.

Also, be care that the any of the following can cause the package to crack or dust to be generated.

1. Applying heat to the external leads for an extended period of time with soldering iron.
2. Applying repetitive bending stress to the external leads.
3. Rapid cooling or heating

**③ OPERATE AND STORAGE ENVIRONMENTS**

Operate in clean environments. CCD image sensors are precise optical equipment that should not be subject to mechanical shocks. Exposure to high temperatures or humidity will affect the characteristics. So avoid storage or usage in such conditions.

Keep in a case to protect from dust and dirt. Dew condensation may occur on CCD image sensors when the devices are transported from a low-temperature environment to a high-temperature environment. Avoid such rapid temperature changes.

For more details, refer to our document "Review of Quality and Reliability Handbook" (C12769E)

**④ ELECTROSTATIC BREAKDOWN**

CCD image sensor is protected against static electricity, but destruction due to static electricity is sometimes detected. Before handling be sure to take the following protective measures.

1. Ground the tools such as soldering iron, radio cutting pliers of or pincer.
2. Install a conductive mat or on the floor or working table to prevent the generation of static electricity.
3. Either handle bare handed or use non-chargeable gloves, clothes or material.
4. Ionized air is recommended for discharge when handling CCD image sensor.
5. For the shipment of mounted substrates, use box treated for prevention of static charges.
6. Anyone who is handling CCD image sensors, mounting them on PCBs or testing or inspecting PCBs on which CCD image sensors have been mounted must wear anti-static bands such as wrist straps and ankle straps which are grounded via a series resistance connection of about 1 MΩ.

[MEMO]

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[MEMO]

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## NOTES FOR CMOS DEVICES

**① VOLTAGE APPLICATION WAVEFORM AT INPUT PIN**

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (MAX) and  $V_{IH}$  (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (MAX) and  $V_{IH}$  (MIN).

**② HANDLING OF UNUSED INPUT PINS**

Unconnected CMOS device inputs can be cause of malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to  $V_{DD}$  or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

**③ PRECAUTION AGAINST ESD**

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it when it has occurred. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

**④ STATUS BEFORE INITIALIZATION**

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

**⑤ POWER ON/OFF SEQUENCE**

In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current.

The correct power on/off sequence must be judged separately for each device and according to related specifications governing the device.

**⑥ INPUT OF SIGNAL DURING POWER OFF STATE**

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements.

Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

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